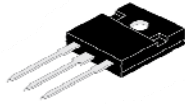


## PNP SILICON EPITAXIAL TRANSISTOR

CSA1943



TO-3P

**TO-3P Leaded  
Plastic Package  
RoHS compliant**

**Complimentary** to PNP type CSC5200

### FEATURE:

This product is available in AEC-Q101 Compliant and PPAP Capable also.

Note: For AEC-Q101 compliant products, please use suffix -AQ in the part number while ordering.

### APPLICATIONS:

1. Power Amplifier Applications.
2. Recommended for 100W High-fidelity Audio Frequency Amplifier Output

### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	VALUE	UNIT
Collector Base Voltage	$V_{CBO}$	230	V
Collector Emitter Voltage	$V_{CEO}$	230	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	15	A
Base Current	$I_B$	1.5	A
Collector Dissipation ( $T_C=25^\circ\text{C}$ )	$P_C$	180	W
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Junction to Case	$R_{\theta(j-c)}$	0.694	$^\circ\text{C/W}$



Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company



**ELECTRICAL CHARACTERISTICS at** (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=50mA, I_B=0$	230	--	--	V
Collector Cut off Current	$I_{CBO}$	$V_{CB}=230V, I_E=0$	--	--	5	$\mu A$
Emitter Cut off Current	$I_{EBO}$	$V_{EB}=5V, I_C=0$	--	--	5	mA
DC Current Gain	$h_{FE} 1$	$I_C=1A, V_{CE}=5V$	80	--	160	
	$h_{FE} 2$	$I_C=7A, V_{CE}=5V$	35	--	--	
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=8A, I_B=0.8A$	--	--	3	V
Base Emitter ON Voltage	$V_{BE(ON)}$	$I_C=7A, V_{CE}=5V$	--	--	1.5	V
Transition Frequency	$f_T$	$I_C=1A, V_{CE}=5V$	--	30	--	MHz
Output Capacitance	$C_{OB}$	$I_E=0, V_{CE}=10V, f=1MHz$	--	240	--	pF

**Notes:**

1. For PNP device voltage and current values will be negative (-).

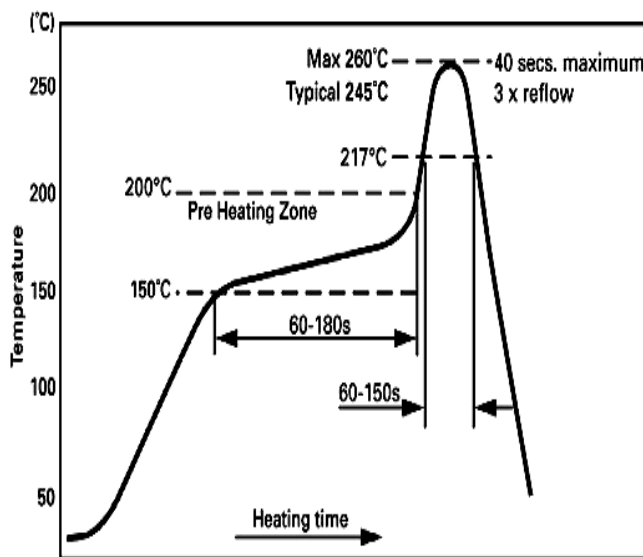
### Recommended Reflow Solder Profiles

The recommended reflow solder profiles for Pb and Pb-free devices are shown below.

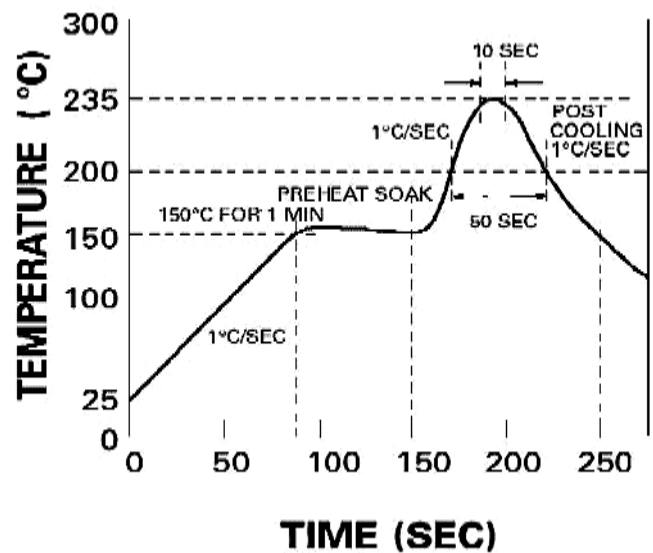
Figure 1 shows the recommended solder profile for devices that have Pb-free terminal plating, and where a Pb-free solder is used.

Figure 2 shows the recommended solder profile for devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with a leaded solder.

**Figure 1**



**Figure 2**



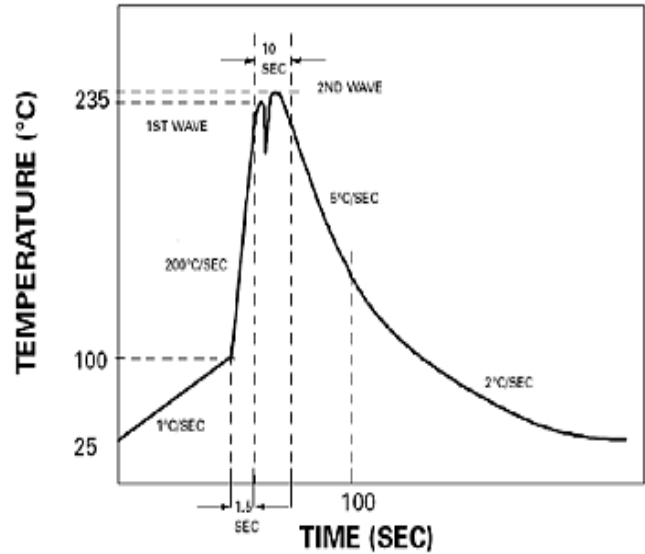
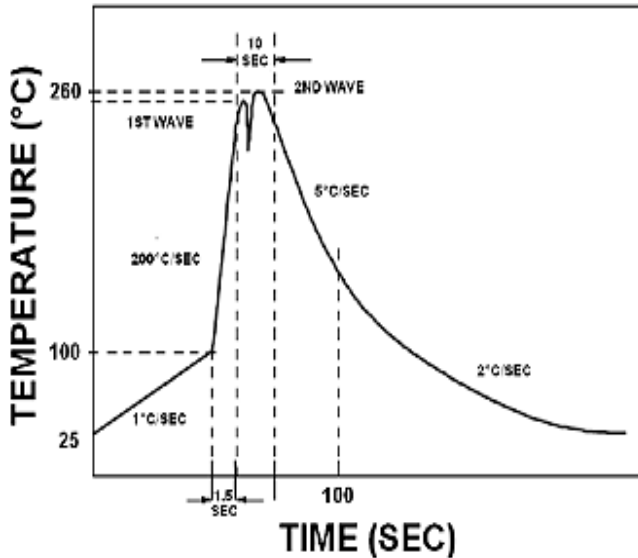
**Reflow profiles in tabular form**

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~3°C/second	~3°C/second
<b>Preheat</b>		
– Temperature Range	150-170°C	150-200°C
– Time	60-180 seconds	60-180 seconds
Time maintained above:		
– Temperature	200°C	217°C
– Time	30-50 seconds	60-150 seconds
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	40 seconds
Ramp-Down Rate	3°C/second max.	6°C/second max.

### Recommended Wave Solder Profiles

The Recommended solder Profile For Devices with Pb-free terminal plating where a Pb-free solder is used

The Recommended solder Profile For Devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with leaded solder



### Wave Profiles in Tabular Form

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~200°C/second	~200°C/second
Heating rate during preheat	Typical 1-2, Max 4°C/sec	Typical 1-2, Max 4°C/Sec
Final preheat Temperature	Within 125°C of Solder Temp	Within 125°C of Solder Temp
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	10 seconds
Ramp-Down Rate	5°C/second max.	5°C/second max

## TYPICAL CHARACTERISTICS CURVES

Fig 1: Collector Current vs Collector Emitter Voltage

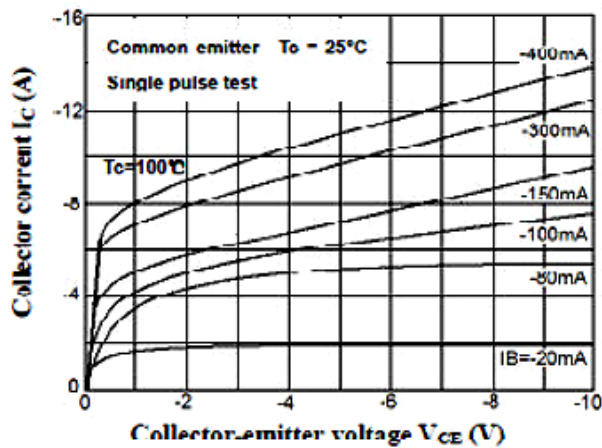


Fig 2: Collector Emitter Saturation Voltage vs Collector Current

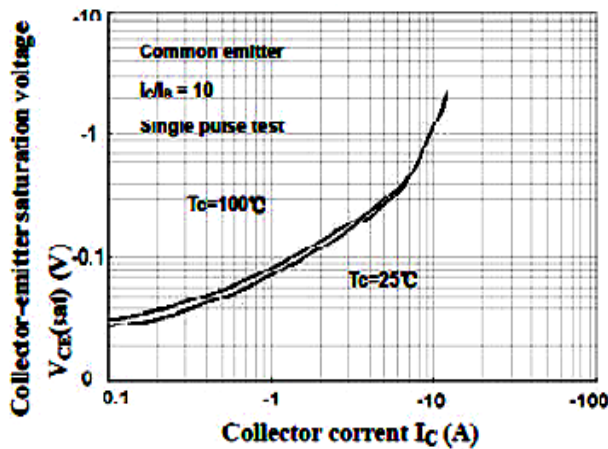


Fig 3: Collector Power Dissipation vs ambient Temp

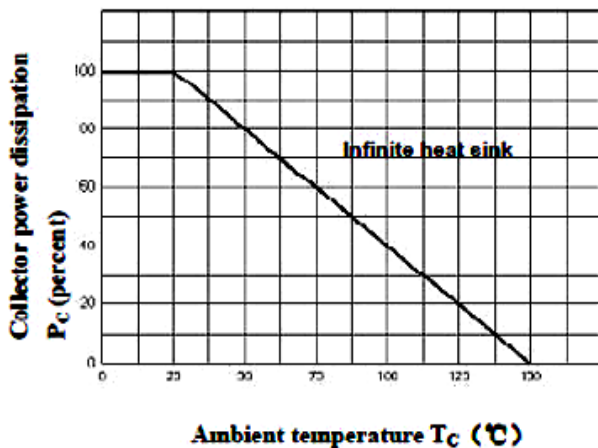


Fig 4: DC Current vs Collector Current

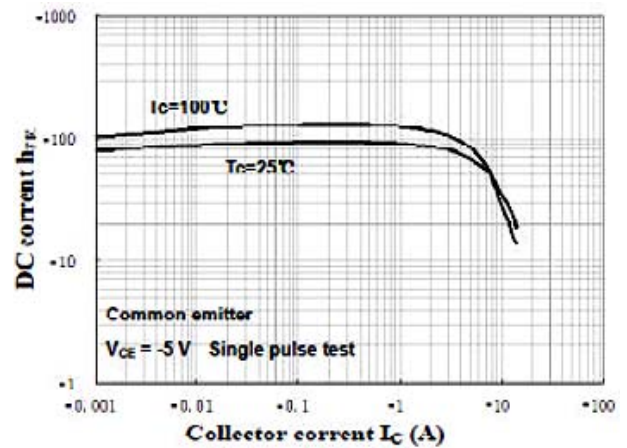


Fig 5: Base-Emitter Saturation Voltage vs Collector Current

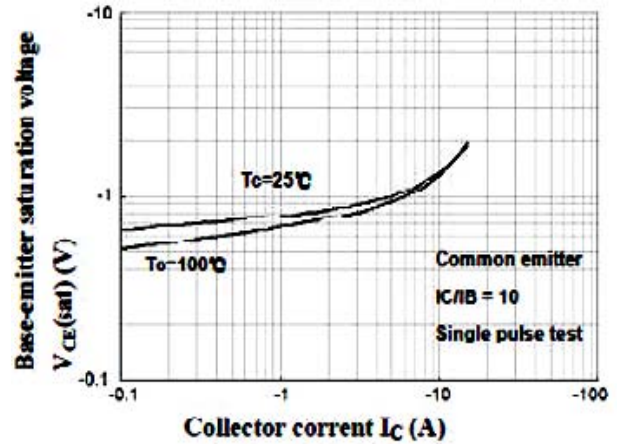
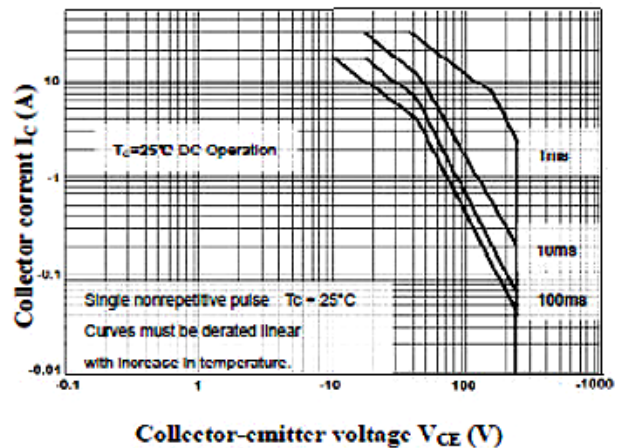
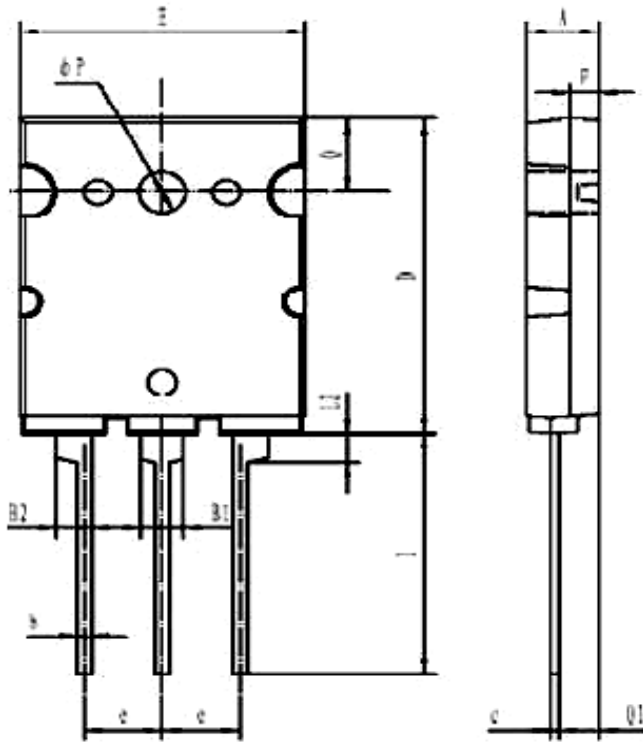


Fig 6: SOA



## PACKAGE DETAILS

### TO-3P Plastic Leaded Package

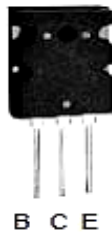


DIM	MIN.	MAX.
A	4.70	5.30
B1	2.80	3.20
B2	2.30	2.70
b	0.80	1.25
c	0.50	0.85
D	25.5	26.5
E	19.5	20.5
e	5.45 (TYP)	
F	1.80	2.20
L	19.5	20.5
L2	2.30	2.70
P	3.10	3.50
Q	5.00	0.20
Q1	2.60	3.00

ALL DIMENSIONS IN MM

### PIN CONFIGURATION

1. BASE
2. COLLECTOR
3. EMITTER





Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company



## Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- Air should be clean.
- Avoid harmful gas or dust.
- Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- Avoid condensation.
- Mechanical stress such as vibration and impact shall be avoided.
- The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

### Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

### Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level		
Level	Time	Condition
1	Unlimited	≤30 °C / 85% RH
2	1 Year	≤30 °C / 60% RH
2a	4 Weeks	≤30 °C / 60% RH
3	168 Hours	≤30 °C / 60% RH
4	72 Hours	≤30 °C / 60% RH
5	48 Hours	≤30 °C / 60% RH
5a	24 Hours	≤30 °C / 60% RH
6	Time on Label(TOL)	≤30 °C / 60% RH





Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company



## Customer Notes

### Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

### Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered trademark of

**Continental Device India Pvt. Limited**

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone +91-11-2579 6150, 4141 1112 Fax +91-11-2579 5290, 4141 1119

email@cdil.com www.cdil.com

CIN No. U32109DL1964PTC004291